NSN 5961-01-383-8375

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Inclosure Material:

Plastic

Overall Length:

Between 2.8 millimeters and 3.0 millimeters

Overall Height:

1.1 millimeters

Overall Width:

2.5 millimeters

Internal Configuration:

Field effect

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 on-state drain to source voltage and 20.0 gate to source voltage

Current Rating Per Characteristic:

0.06 amperes drain current and 1.00 amperes off-state current, peak

Power Rating Per Characteristic:

0.25 watts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0